## **Triacs**

df.dzsc.com

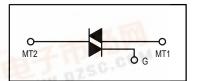
## **Silicon Bidirectional Triode Thyristors**

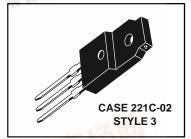
... designed primarily for industrial and consumer applications for full wave control of ac loads such as appliance controls, heater controls, motor controls, and other power switching applications.

- All Diffused and Glass-Passivated Junctions for Parameter Uniformity and Stability
- Small, Rugged, Thermowatt Construction for Low Thermal resistance and High Heat Dissipation
- Center Gate Geometry for Uniform Current Spreading
- Gate Triggering Guaranteed in Three Modes (MAC229FP Series) or Four Modes (MAC229AFP Series)

# MAC229FP Series MAC229AFP Series

TRIACs 8 AMPERES RMS 200 thru 800 VOLTS





#### **MAXIMUM RATINGS** (T<sub>J</sub> = 25°C unless otherwise noted.)

Rating Symbo		Value	Unit	
Peak Repetitive Off-State Voltage(1)  (T <sub>J</sub> = -40 to 110°C, 1/2 Sine Wave 50 to 60 Hz, Gate Open)  MAC229-4FP, MAC229A4FP  MAC229-6FP, MAC229A6FP  MAC229-8FP, MAC229A10FP	V <sub>DRM</sub>	200 400 600 800	Volts	
On-State RMS Current (T <sub>C</sub> = 80°C) Full Cycle Sine Wave 50 to 60 Hz	I <sub>T(RMS)</sub>	8	Amps	
Peak Non-repetitive Surge Current (One Full Cycle 60 Hz, T <sub>J</sub> = 110°C)	ITSM	80	Amps	
Circuit Fusing (t = 8.3 ms)	l <sup>2</sup> t	26	A <sup>2</sup> s	
Peak Gate Current (t ≤ 2 μs)	I <sub>GM</sub>	±2	Amps	
Peak Gate Voltage (t ≤ 2 μs)	V <sub>GM</sub>	V <sub>GM</sub> ±10		
Peak Gate Power (t ≤ 2 μs)	PGM	P <sub>GM</sub> 20		
Average Gate Power (T <sub>C</sub> = 80°C, t ≤ 8.3 ms)	P <sub>G</sub> (AV)	PG(AV) 0.5		
Operating Junction Temperature Range	TJ	Т <sub>Ј</sub> —40 to 110		
Storage Temperature Range	T <sub>stg</sub>	-40 to 150	°C	
Mounting Torque		8	in. lb.	

V<sub>DRM</sub> for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the
voltage ratings of the devices are exceeded.
 The case temperature reference point for all TC measurements is a point on the center lead of the package as close as possible to the plastic

#### **MAC229FP Series MAC229AFP Series**

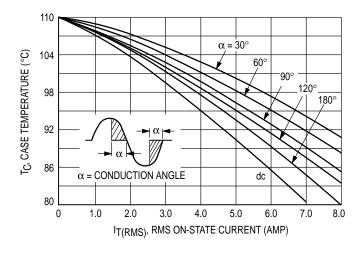
#### THERMAL CHARACTERISTICS

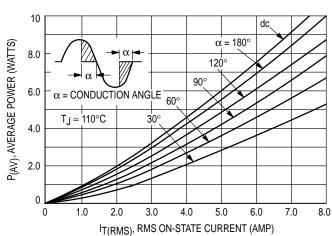
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{ heta JC}$	2.2	°C/W
Thermal Resistance, Case to Sink	R <sub>0</sub> CS	2.2 (typ)	°C/W
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	60	°C/W

### **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C and either polarity of MT2 to MT1 voltage unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
Peak Blocking Current(1) $(V_D = Rated \ V_{DRM}, \ Open \ Gate)$ $T_J = 25^{\circ}C$ $T_J = 110^{\circ}C$	IDRM		=	10 2	μA mA
Peak On-State Voltage (I <sub>TM</sub> = 11 A Peak, Pulse Width ≤ 2 ms, Duty Cycle ≤ 2%)	Vтм	_	_	1.8	Volts
Gate Trigger Current (Continuous dc) $ (V_D=12\ V,\ R_L=100\ \Omega) \\ MT2(+),\ G(+);\ MT2(+),\ G(-);\ MT2(-),\ G(-) \\ MT2(-),\ G(+)\ "A"\ Suffix\ Only $	<sup>I</sup> GT	_ _ _		5 10	mA
Gate Trigger Voltage (Continuous dc) $ (V_D = 12 \text{ V}, R_L = 100 \Omega) \\ \text{MT2(+)}, G(+); \text{MT2(+)}, G(-); \text{MT2(-)}, G(-) \\ \text{MT2(-)}, G(+) \text{ "A" Suffix Only} \\ (V_D = \text{Rated } V_{DRM}, T_C = 110^{\circ}\text{C}, R_L = 10 \text{ k}) \\ \text{MT2(+)}, G(+); \text{MT2(+)}, G(-); \text{MT2(-)}, G(-) \\ \text{MT2(-)}, G(+) \text{ "A" Suffix Only} $	V <sub>G</sub> T	  0.2 0.2	_ _ _ _	2 2.5 — —	Volts
Holding Current (V <sub>D</sub> = 12 Vdc, I <sub>TM</sub> = 200 mA, Gate Open)	lн	_	_	15	mA
Gate-Controlled Turn-On Time $(V_D = Rated V_{DRM}, I_{TM} = 16 A Peak, I_G = 30 mA)$	tgt	_	1.5	_	μs
Critical Rate of Rise of Off-State Voltage (V <sub>D</sub> = Rated V <sub>DRM</sub> , Exponential Waveform, T <sub>C</sub> = 110°C)	dv/dt	_	25	_	V/µs
Critical Rate of Rise of Commutation Voltage (V <sub>D</sub> = Rated V <sub>DRM</sub> , I <sub>TM</sub> = 11.3 A, Commutating di/dt = 4.1 A/ms, Gate Unenergized, T <sub>C</sub> = 80°C)	dv/dt(c)	_	5	_	V/μs

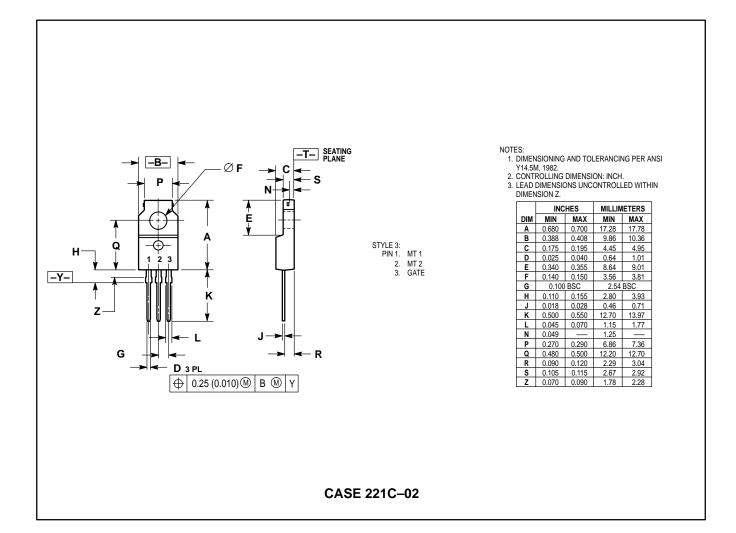
<sup>1.</sup> Ratings apply for open gate conditions. Devices shall not be tested with a constant current source for blocking voltage such that the voltage applied exceeds the rated blocking voltage.





#### **MAC229FP Series MAC229AFP Series**

#### **PACKAGE DIMENSIONS**



#### **MAC229FP Series MAC229AFP Series**

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